

1200V / 300A 2 in one-package

■ Features

- VCE(sat) classified for easy parallel connection
- High speed switching
- Voltage drive
- Low inductance module structure

■ Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as Welding machines

■ Maximum ratings and characteristics

● Absolute maximum ratings (at Tc=25°C unless otherwise specified)

| Item | Symbol | Rating | Unit |
|---------------------------|------------------|-----------------------|-------|
| Collector-Emitter voltage | V _{CES} | 1200 | V |
| Gate-Emitter voltage | V _{GES} | ±20 | V |
| Collector current | Continuous | I _C | 300 A |
| | 1ms | I _C pulse | 600 A |
| | | -I _C | 300 A |
| | 1ms | -I _C pulse | 600 A |
| Max. power dissipation | P _C | 2100 | W |
| Operating temperature | T _j | +150 | °C |
| Storage temperature | T _{stg} | -40 to +125 | °C |
| Isolation voltage | V _{is} | AC 2500 (1min.) | V |
| Screw torque | Mounting *1 | 3.5 | N·m |
| | Terminals *2 | 4.5 | N·m |

*1 : Recommendable value : 2.5 to 3.5N·m (M5) or (M6)

*2 : Recommendable value : 3.5 to 4.5N·m (M6)

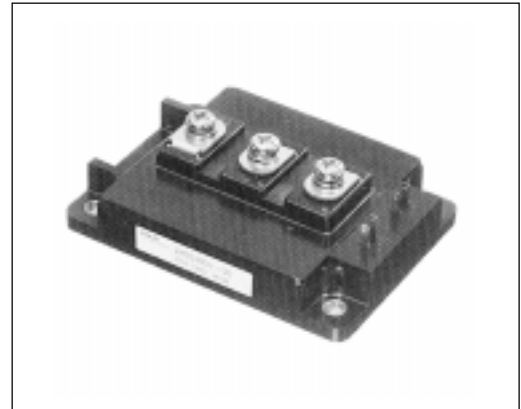
● Electrical characteristics (at T_j=25°C unless otherwise specified)

| Item | Symbol | Characteristics | | | Conditions | Unit |
|--------------------------------------|-----------------------|-----------------|-------|------|--|------|
| | | Min. | Typ. | Max. | | |
| Zero gate voltage collector current | I _{CES} | - | - | 3.0 | V _{GE} =0V, V _{CES} =1200V | mA |
| Gate-Emitter leakage current | I _{GES} | - | - | 45 | V _{CES} =0V, V _{GES} =±20V | μA |
| Gate-Emitter threshold voltage | V _{GE(th)} | 4.5 | - | 7.5 | V _{CES} =20V, I _C =300mA | V |
| Collector-Emitter saturation voltage | V _{CES(sat)} | - | - | 3.3 | V _{GE} =15V, I _C =300A | V |
| Input capacitance | C _{ies} | - | 48000 | - | V _{GE} =0V | pF |
| Output capacitance | C _{oes} | - | 17400 | - | V _{CES} =10V | |
| Reverse transfer capacitance | C _{res} | - | 15480 | - | f=1MHz | |
| Turn-on time | t _{on} | - | - | 1.2 | V _{CC} =600V | μs |
| | t _r | - | 0.25 | 0.6 | I _C =300A | |
| Turn-off time | t _{off} | - | - | 1.5 | V _{GE} =±15V | |
| | t _f | - | 0.35 | 0.5 | R _G =2.7ohm | |
| Diode forward on voltage | V _F | - | - | 3.0 | I _F =300A, V _{GE} =0V | V |
| Reverse recovery time | t _{rr} | - | - | 0.35 | I _F =300A | μs |

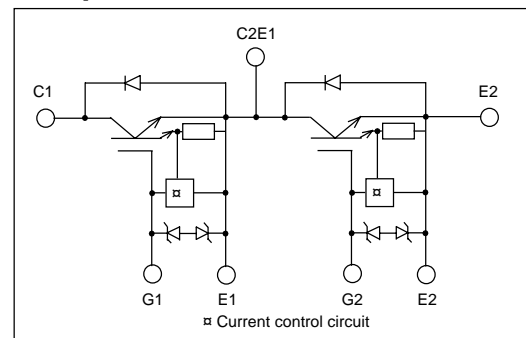
● Thermal resistance characteristics

| Item | Symbol | Characteristics | | | Conditions | Unit |
|--------------------|-----------------------|-----------------|--------|------|-------------------------|------|
| | | Min. | Typ. | Max. | | |
| Thermal resistance | R _{th(j-c)} | - | - | 0.06 | IGBT | °C/W |
| | R _{th(j-c)} | - | - | 0.15 | Diode | °C/W |
| | R _{th(c-f)*} | - | 0.0167 | - | the base to cooling fin | °C/W |

* : This is the value which is defined mounting on the additional cooling fin with thermal compound



■ Equivalent Circuit Schematic

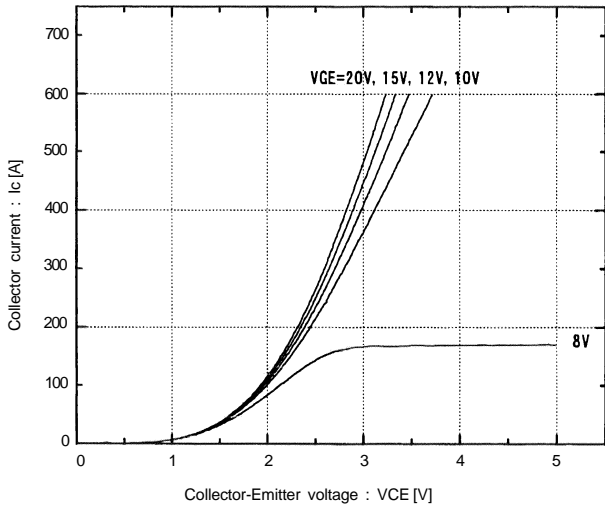


● VCE(sat) classification

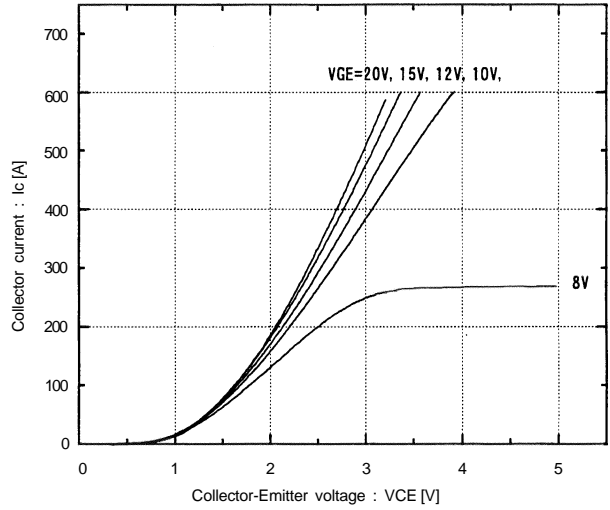
| Rank | Lenge | Conditions |
|------|---------------|---|
| F | 2.25 to 2.50V | I _C = 300A V _{GE} = 15V T _j = 25°C |
| A | 2.40 to 2.65V | |
| B | 2.55 to 2.80V | |
| C | 2.70 to 2.95V | |
| D | 2.85 to 3.10V | |
| E | 3.00 to 3.30V | |

■ Characteristics (Representative)

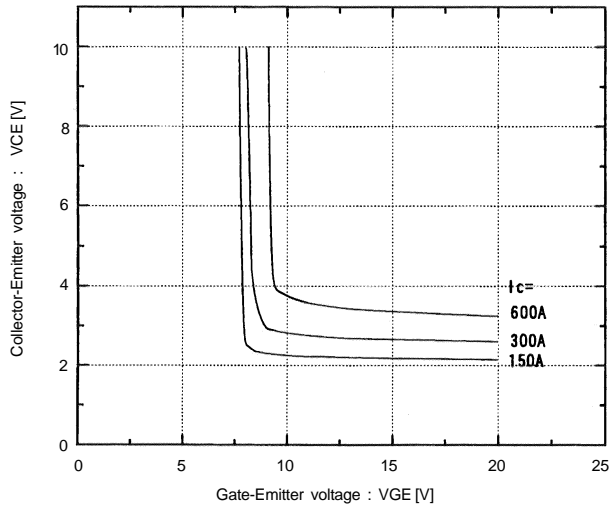
Collector current vs. Collector-Emitter voltage
T_j=25°C



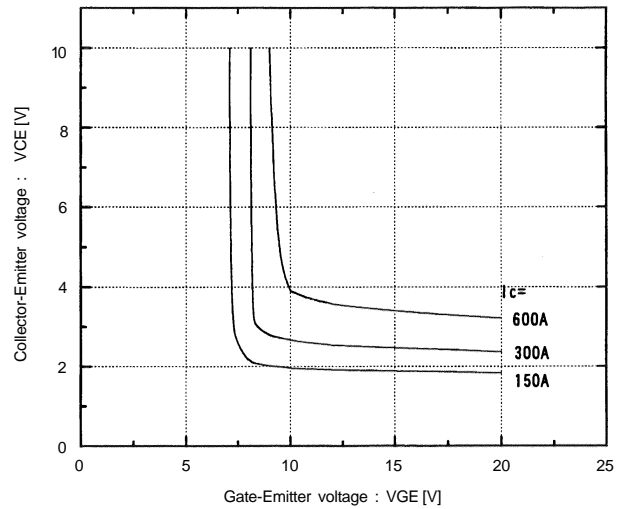
Collector current vs. Collector-Emitter voltage
T_j=125°C



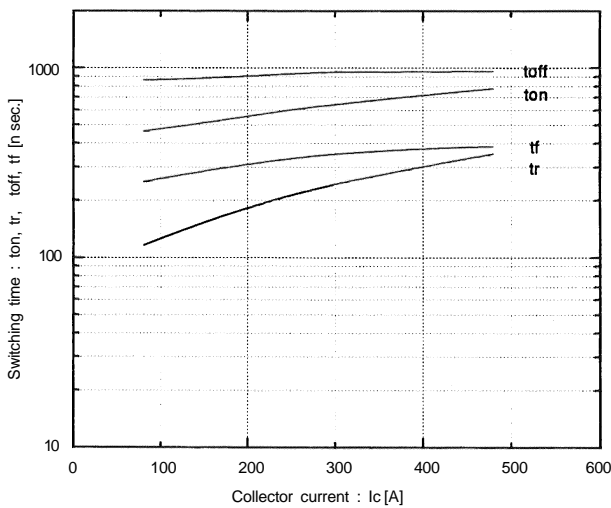
Collector-Emitter vs. Gate-Emitter voltage
T_j=25°C



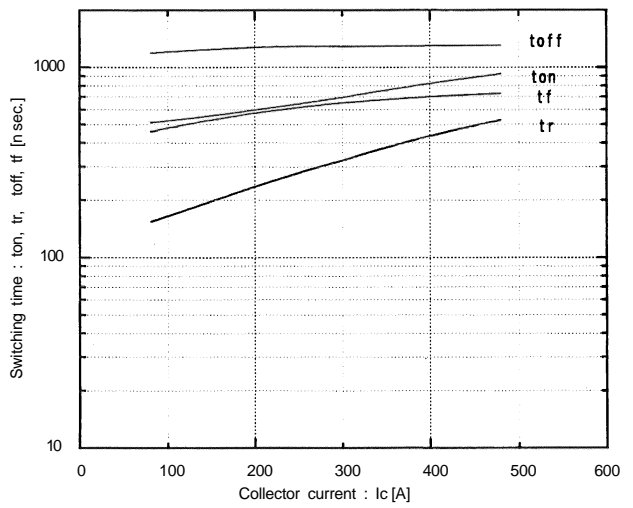
Collector-Emitter vs. Gate-Emitter voltage
T_j=125°C



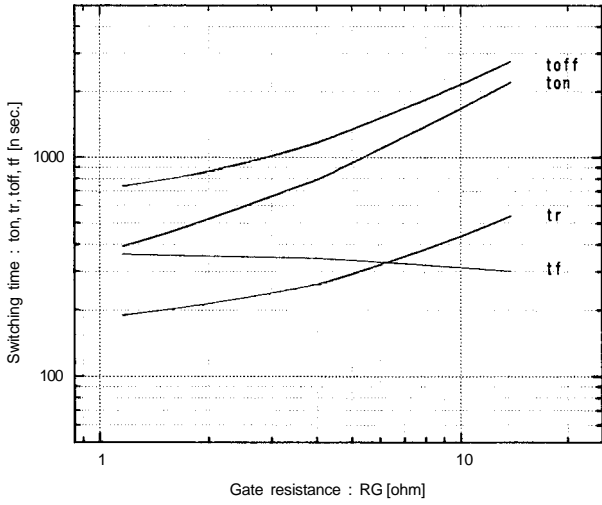
Switching time vs. Collector current
V_{cc}=600V, R_G=2.7 ohm, V_{GE}=±15V, T_j=25°C



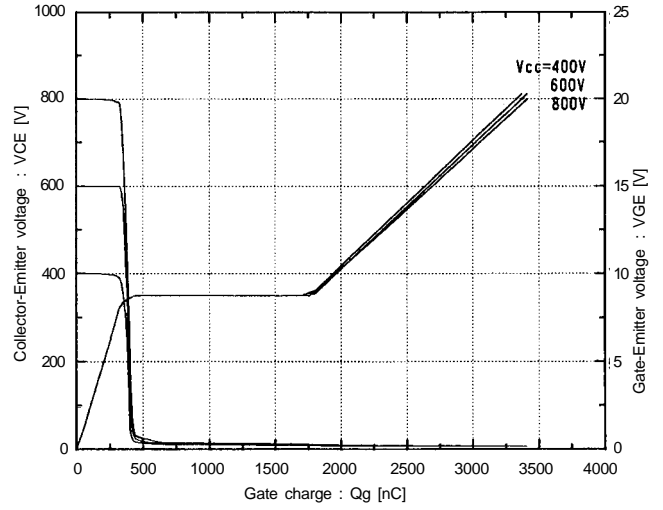
Switching time vs. Collector current
V_{cc}=600V, R_G=2.7 ohm, V_{GE}=±15V, T_j=125°C



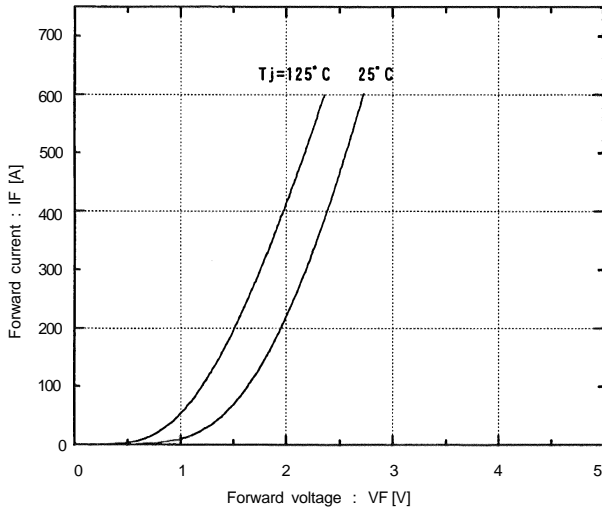
Switching time vs. RG
 $V_{CC}=600V, I_c=300A, V_{GE}=\pm 15V, T_J=25^\circ C$



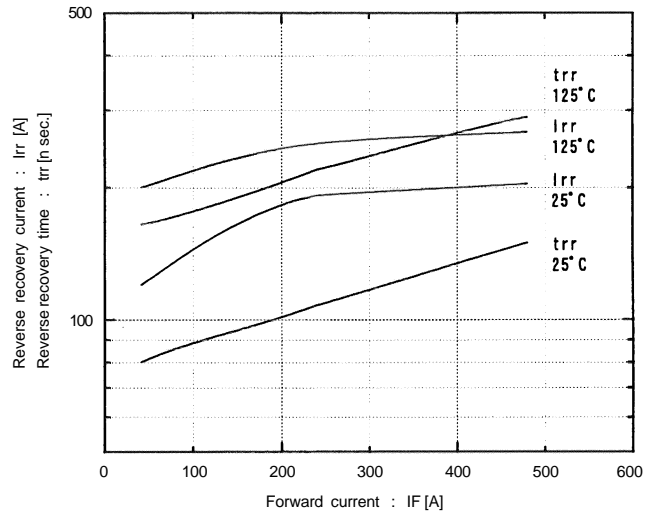
Dynamic input characteristics
 $T_J=25^\circ C$



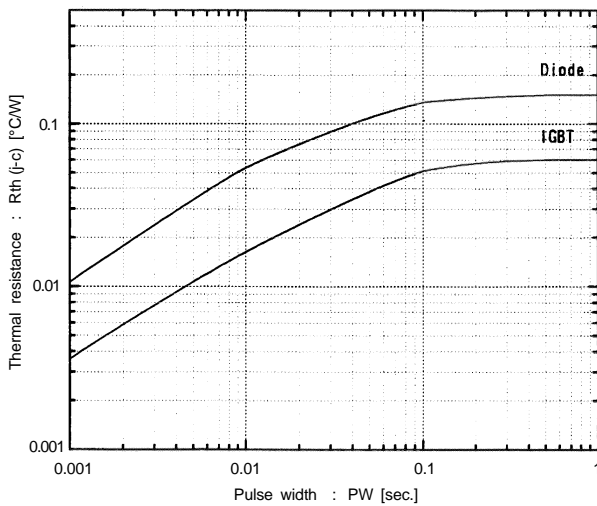
Forward current vs. Forward voltage
 $V_{GE}=0V$



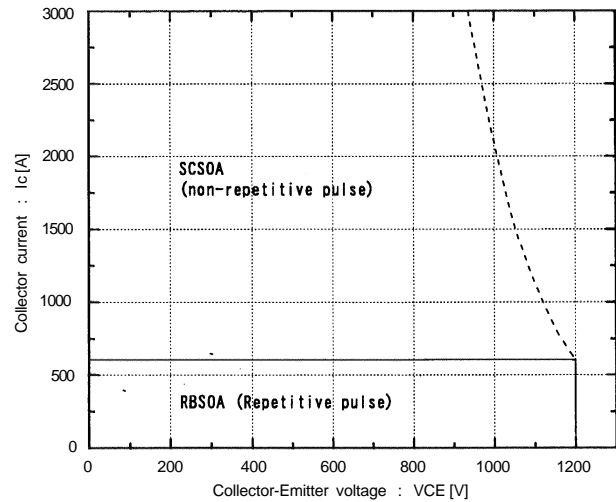
Reverse recovery characteristics
 t_{rr}, I_{rr} vs. I_F

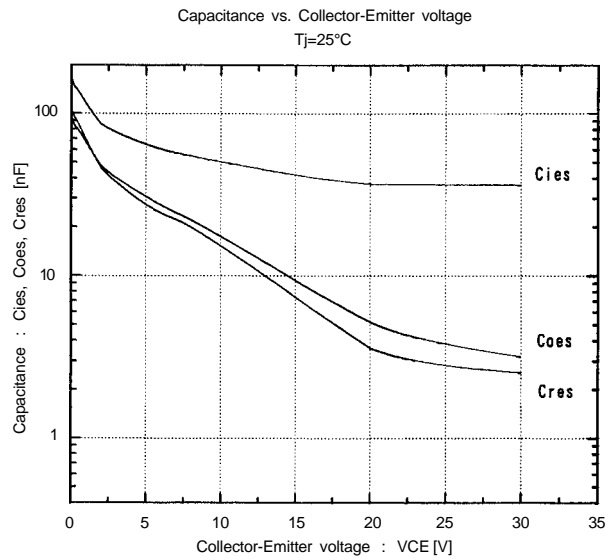
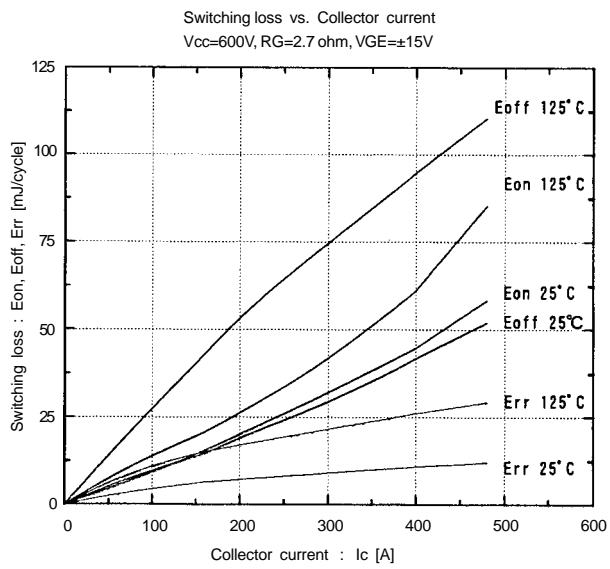


Transient thermal resistance



Reversed biased safe operating area
 $+V_{GE}=15V, -V_{GE} \le 15V, T_J \le 125^\circ C, R_G \ge 2.7 \text{ ohm}$





■ Outline Drawings, mm

